NSN 5961-00-418-2482

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-418-2482 **Inclosure Material:** Glass **Overall Length:** 0.155 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.071 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 400.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

No Fiig: A110a0